Wide-field parallel mapping of local spectral and topographic information with white light interference microscopy

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Fourier analysis of interferograms captured in white light interference microscopy is proposed for performing simultaneous local spectral and topographic measurements at high spatial resolution over a large field of view. The technique provides a wealth of key information on local sample properties. We describe the necessary processing and calibration involved to produce reflectivity maps of spatially extended samples. This enables precise and fast identification between different materials at a local scale of $1 \mu m$. We also show that the recovered spectral information can be further used for improving topography measurements, particularly in the case of samples combining dielectric and conducting materials in which the complex refractive index can result in nanometric height errors. © 2020 Optical Society of America

Optical spectrometers and ellipsometers are the main systems used to measure the spectroscopic information of materials. The former uses the principles of dispersion or Fourier-Transform spectroscopy, while the latter are based on the measurement of the change in polarization. The spectral information obtained is averaged over the illumination spot size of the instruments, which typically covers several mm² for standard spectrometers [1], down to thousands of μm^2 for ellipsometers. These systems cannot therefore provide spectral measurement of materials at the micrometer scale, nor perform imaging over microscopic areas. For samples with micrometric dimensions, new methods for measuring spectral information with a very high spatial resolution have been developed, such as s-SNOM (Spectral Scanning Near-field Optical Microscopy) [2] and hyperspectral imaging microscopy [3,4]. Nevertheless, as the former is a pointwise measurement technique, it requires long scanning times to image a large area of the sample, while the latter requires scanning in either the spatial or the spectral domains.

Fast growth in new nanotechnologies and more advanced studies of living matter at the micrometer/nanometer scale have generated increasing demands in the high resolution and speed of local characterizations [2-4]. To meet these requirements, White Light Interference Microscopy (WLIM) has become a standard tool for surface roughness and 3D structural measurement at the microscopic scale. The full-field imaging capability [5] enables measurements of surface topography and roughness with both high lateral resolution (about 400 nm) and axial sensitivity (a few nm) over relatively large Fields of View (FoV). Fast processing techniques such as Phase Shifting Microscopy (PSM) and Coherence Scanning Interferometry (CSI) [5-7] are typically used to recover topographic information. The addition of a color camera to such a system enables material identification to a certain extent [8] but because it is not quantitative, would not be able to distinguish between two similar looking or metamer colored materials [9]. On the other hand, by using an approach based on performing a Fourier Transform of the fringe signal, quantitative spectral information can be obtained locally [10-12]. This information can also be resolved over depth under certain illumination conditions if the sample is transparent [12]. This method has also been successfully applied for measuring the reflectivity of thin and thick films in order to deduce their local thickness and dispersion law [13,14].

In this paper we present how WLIM can provide simultaneous 3D spatial and spectral 2D maps of materials with micrometer lateral resolution by using a single axial scan. Signal processing similar to that used in classical Fourier-Transform spectroscopy is used but without the need for an additional spectrometer. Given the full-field imaging ability of WLIM, this method allows fast acquisition of the spectral information over a large area, whilst preserving the capacity for distinguishing spectrally different materials with micrometric dimensions.

CSI consists in acquiring the interferometric signal over depth (Z) within a large area (XY) of the sample measured as illustrated in Fig. 1(a). The signal is extracted over depth pixel by pixel (Fig. 1(b)) and then processed to obtain information about the sample reflectivity in

different Regions Of Interest (ROI). Since white light is used, the intensity of the interferometric signal *I* corresponds to the sum of the interference signals at each wavelength λ , as given by Eq. (1):

$$I(z) = \int_{\omega_{1}}^{\omega_{2}} \frac{S_{sys}(\omega)}{4} \left(R_{ref}(\omega) + R_{sam}(\omega) \right) + \frac{S_{sys}(\omega)}{2} \sqrt{R_{ref}(\omega)} \sqrt{R_{sam}(\omega)} \cos\left(\Delta\varphi(\omega, z) + \Phi\right) d\omega$$
(1)

where ω is the frequency and ω_1 and ω_2 are the bandwidth limits of the source. S_{Sys} is the spectral response of the whole system, given by the product of the source spectrum, the spectral response of the camera and the spectral transmittance of the entire optical system. R_{ref} and R_{som} are the reflectivity of the reference mirror and the sample analyzed respectively. $\Delta \varphi$ is the phase difference between the reference and the object arms, and Φ is the phase on reflection error.

The processing then consists in removing the offset in Eq. (1) and conserving only the part modulated by the cosine function. For spectral analysis, the optical path difference δ and the wavenumber σ , defined as the inverse of the wavelength, are used. The limits of the integral are extended to infinity (with the spectral response equal to 0 outside the boundaries ω_1 and ω_2). Finally, a Fourier Transform (FT) is applied, and its modulus gives the spectral response of the system multiplied by the sample and reference mirror reflectivity, as presented in Eq. (2). This result is known as the Non-Calibrated Spectral response (*NCS*).

$$\left|FT\left[I\left(\delta\right)\right]\right| = \frac{1}{4}S_{sys}\left(\sigma\right)\sqrt{R_{ref}\left(\sigma\right)}\sqrt{R_{sam}\left(\sigma\right)} = NCS\left(\sigma\right)$$
(2)

To determine the sample reflectivity, S_{SYS} and R_{ref} are estimated beforehand through a calibration step. This consists in measuring the *NCS* of a calibration sample (a silicon wafer in our case) having a spectral reflectivity previously measured using a classic optical spectrometer. According to Eq. (2), the value of $S_{SYS}(\sigma)$.[$R_{ref}(\sigma)$]^{1/2} can then be determined, which is independent of the sample and specific to the system. This product is the Spectral Transfer Function (*STF*). Finally, by keeping the same parameters (i.e. source intensity and optical arrangement) for the measurement step as in the calibration step, the reflectivity of any sample can be determined quantitatively pixel by pixel with the formula given in Eq. (3):

$$R_{sam}(\sigma) = \left|\frac{NCS(\sigma)}{STF(\sigma)}\right|^2$$
(3)

The system used to conduct the experiments is composed of a white light interferometer in a Linnik configuration mounted on a breadboard [15] as illustrated in Fig. 1(c). The effects of environmental noise are reduced by placing the whole system in a special temperaturecontrolled anti-vibration room mounted on air cushions. The light emitted by the white LED (Thorlabs MBB1L3) passes through the Köhler illuminator and is then divided into two beams by the beamsplitter. Both the reference and object beams travel through identical long-working distance Mitutoyo objectives (M Plan Apo 20x/0.42, infinity corrected), before being reflected by a reference mirror (RM) and the sample. These reflected beams are recombined to produce a fringe pattern superimposed on the sample image, which is captured using a 16-bit cooled camera (PCO Edge 4.2 USB 3.0). The sample is placed on a position controlled piezo stage (PZT PI P621-ZCD) to allow scanning along the optical axis with nanometer sensitivity. The setup is controlled by homemade software developed in LabVIEW. The setup parameters between the calibration and the measurement steps stay the same. To avoid any spectrum distortion caused by large illumination apertures [16], the aperture diaphragm (AD) is closed during the image



Fig. 1. (a) XYZ stack of interferometric images. (b) Interferometric signal extracted at one pixel. (c) Layout of the white light interferometer used to perform the experiments. The aperture diaphragm (AD) controls the illumination angle cone and the field diaphragm (FD) the field of view. The Tube Lens (TL) produces the image on the camera.

capture. A 3x3 pixel averaging filter is applied to each interferometric image to reduce camera-related noise (readout and dark current) before processing. Due to the larger size of the Airy diffraction disk (about 1 µm) compared to the 3x3 pixel area, no information is lost in terms of lateral resolution. The interferometric stack is acquired over a depth of 10 μ m, with a piezoelectric displacement step of $\lambda/8$. With an effective wavelength of 660 nm being used in this setup, the piezo step is equal to 82.5 nm. Each interferometric image is obtained using temporal averaging of 10 images. The packet of interference fringes is windowed with a 9 µm wide Hamming apodization window. A zeropadding operation followed by interpolation enables the reflectivity to be then displayed with a step of 1 nm, although this does not correspond to the spectral resolution. This latter value depends mostly on the apodization window width, the wider the interferogram, the better being the spectral resolution. The use of a 9 µm wide Hamming window leads to an estimated spectral resolution of about 25 nm at λ =500 nm and 44 nm at λ =660 nm according to the FT sampling. As suggested in [17], averaging of the reflectivity is performed over 6 processed interferometric stacks to obtain more accurate spectral information. This allows a good trade-off to be maintained between accuracy and acquisition time (\sim 5 min). The repeatability of the standard deviation (Std) to the averaged reflectivity ratio, Std(R)/R, was measured to be 0.02 when making 25 identical successive measurements over 3 hours. The spectral results hereafter are displayed with their spatial Std, which gives an idea of the minimum reflectivity difference that would be identifiable. Processing of the whole field of view (401x404 pixels² =130x131 μ m²) is performed using MATLAB to take advantage of the matrix computing power and only requires a little less than 2 min on a PC equipped with an Intel i7-960 processor and 24 Go RAM.

The validity of the proposed method was first demonstrated by identifying two different materials through their spectral properties. A thin gold layer (~50 nm) was deposited onto an aluminum substrate. As illustrated in Fig. 2(a), the image captured with the camera does not allow an easy identification of which part of the sample is composed of aluminum or gold, as the gray level intensity measured by the camera is similar for both materials. With the method presented above, it is possible to extract multiple reflectivity maps, three of which are displayed in Fig. 2(b), (c) and (d) for the wavelengths 500 nm, 575 nm and 750 nm. This provides a clear distinction between the materials based on their reflectivity at the chosen wavelength. Although the 575 nm reflectivity map presents an almost similar spectral response for each material (about 90%), the 500 nm map, where the lower and



Fig. 2. (a) Gray-level image of gold on aluminum sample. Reflectivity map at a wavelength of 500 nm (b), 575 nm (c), 750 nm (d) and with 1 nm steps from 500 nm to 800 nm in Visualization 1. (e) Spectral cross section along the blue line in (a). (f) Reflectivity as a function of the wavelength from the cyan square (ROI 1) and green square (ROI 2) in (a) compared to theoretical data: red dashed line for aluminum and black dotted line for gold.

upper parts have a reflectivity of about 55% and 90% respectively is particularly relevant for identifying the presence of the two different materials. It should be noted that at this wavelength the influence of the noise is more significant, which is explained by the LED emission intensity that substantially decreases below 520 nm and above 775 nm. This leads to a STF closer to 0 at these wavelengths and thus to a greater measurement uncertainty, as shown with increasing Std values Fig. 2(f). In Visualization 1, the reflectivity map is displayed from 500 nm to 800 nm in steps of 1 nm. The spectral cross-section in Fig. 2(e), taken along the blue line in Fig. 2(a), also clearly shows the heterogeneity of the sample composition. The plot in Fig. 2(f) is obtained by analyzing the average and standard deviation reflectivities measured in a $3.25 \times 3.25 \,\mu\text{m}^2$ area represented in cyan (labelled ROI 1) in the upper part and in green (labelled ROI 2) in the lower part in Fig.2(a). Theoretical reflectivities for aluminum and gold [18] are represented by the red dashed line and black dotted line in Fig. 2(f). The shape of the reflectivity spectra together with the reflectivity maps make it possible to deduce that the upper material is aluminum and the lower one is gold.

The spectral characterization of the samples presented above only uses the magnitude of the FT to determine the reflectivity. The angle $\Delta \varphi$ given by the phase of the FT provides different information and can be used to extract the sample topography *h*, as shown by Eq. (4):

$$h(x, y) = \frac{1}{4\pi} \frac{d(\Delta \varphi)}{d\sigma} \text{ with } \Delta \varphi(\sigma) = \arg \left\{ FT \left[I(x, y, \delta) \right] \right\}$$
(4)

This is similar to that used in Fourier Domain Analysis [19], which combines the advantages of CSI and PSM, that is, an axial sensitivity of a few nm with the removal of the $\lambda/2$ steps uncertainty. Consequently, all the information contained in the FT of the interferogram is used, resulting in simultaneous mapping of spectral reflectivity and topographic information. These are obtained from the same captured image data. The result provided by the Eq. (4) is used to command the unwrapping of the topography obtained from the phase value at a wavelength of λ =671 nm for which the signal to noise ratio is optimal.



Fig. 3. (a) Reflectivity map at λ =525 nm for a sample made of gold deposited on an aluminum substrate. (b) Binary map extracted from (a) after image processing. Topography measured with the proposed method before (c) and after (d) reflection phase shift difference correction. (e) Topography measured with AFM. (f) Profile extracted from each topographic map in centerline in green, blue and red respectively for CSI without and with correction and AFM.

As the sample measured is composed of two distinct metals, different phase shifts are introduced on reflection [20]. At this wavelength, the phase shift reflection for unpolarized light is equal to ~1.314 rad for gold [21] and ~1.450 rad for aluminum [22], leading to a phase shift difference of 0.137 rad or a height difference of 14.6 nm. To correct the error, the material location needs to be identified. This is easily achieved using the parallel measurement of the spectral response. For instance, the spectral map is extracted at λ =525 nm, as shown in Fig. 3(a). At this wavelength, the reflectivity of the gold is about 75% compared to about 90% for the aluminum. The binary map in Fig. 3(b) is obtained via Otsu's binarization algorithm of the reflectivity map in (a) followed by a 3x3 median filter and successive morphological closing and opening with a 3-pixels radius structuring element to remove the points missed in the binarization process. The aluminum and gold are defined by values of 1 and 0. Now that the materials are computationally identified, the height correction between the aluminum and gold can be applied. The topographies before and after correction are illustrated in Fig. 3(c) and (d). They are compared to the topography obtained in Fig. 3(e) using an AFM Park Systems XE-70 and used as a gold-standard reference measurement (z-resolution about 1 nm in air in the noncontact mode). A profile in the center of each topographic view is plotted in Fig. 3(f) for comparison. After correction, the proposed technique provides a height measurement that matches very well with that obtained from the AFM system. Indeed, the average height is equal to 42±0.5 nm after correction and 41±3 nm with the AFM. The small difference can be explained by the system noise, the measurement location which can be slightly different between each system and the phase shift value chosen [21,22]. The error is only 2.22% and below 1 nm. As a comparison an error of 33.35% would have been obtained without the correction method proposed.

Finally, local reflectivity measurements were performed on a microstructured element. The sample is a negative 1951-USAF resolution target standard (Model Edmund Optics #38-256) made of a deposition of chromium on a glass substrate. The element 1 of the group 6 was imaged in Fig. 4(a). Fig. 4(b) shows the 660 nm reflectivity map. The 8 µm glass lines are clearly contrasted with a reflectivity of about 4%



Fig. 4. (a) Gray-level image of the negative 1951-USAF resolution target. (b) Reflectivity map at a wavelength of 660 nm, and with 1 nm steps from 500 nm to 800 nm in Visualization 2. (c) Reflectivity as a function of the wavelength from the cyan square (ROI 1), green square (ROI 2) and red square (ROI 3) in (a) compared to theoretical data: yellow dashed line for chromium and black dotted line for glass. (d) Topography measured with interferometer after phase on reflection difference correction.

compared to the chromium whose reflectivity is about 58%. Fig. 4(c) gives the average and standard deviation of several reflectivity spectra obtained by analyzing each pixel inside the 3.25x3.25 µm² cyan and green areas (labelled as ROI 1 and 2) plotted in Fig. 4(a). Theoretical reflectivities for chromium and glass are plotted in yellow dashed and black dotted lines in Fig. 4(c) for comparison, showing a very good match between the theoretical and measured spectra. While the shapes of the simulated and measured chromium reflectivity spectra are identical, there is a 2.5% offset difference between them. This can be explained by the properties of the chromium used in the simulation that might slightly vary from the material used in the experiment. A variation in the light intensity between the calibration and measurement steps could also provide another explanation. The quasi-constant reflectivity of both the chromium and glass in the visible spectral range is well represented in Fig. 4(c) and also in the Visualization 2 presenting the 2D reflectivity map evolution from 500 nm to 800 nm in steps of 1 nm. These results illustrate the ability of the method to distinguish the nature of the material from um-sized elements. It also highlights its benefits compared to classical spectral measurement devices. Indeed, the reflectivity measured with a standard spectrometer would have been at best similar to the reflectivity spatially averaged (shown in Fig. 4(c)) over the $40x40 \,\mu\text{m}^2$ red square plotted in Fig. 4(a) (labelled ROI 3). In this case the information from both materials is mixed together preventing any spatially-resolved analysis and further sample identification. As explained previously, the topography can also be obtained by analyzing the phase of the same data set acquired. Light reflection on a chromium surface leads to an error in the measured height of 14.5 nm at λ =671 nm [23], which can be corrected by applying the method detailed previously. The chromium position is identified via spectral characterization and its topography subsequently corrected (Fig. 4(d)). The comparison with an AFM measurement across the vertical glass line gives an average height of 76.5±1.5 nm. With the proposed method an average height of 70.5±1 nm is obtained after correction. The possible source of errors is identical to those discussed previously and can explain the difference of 6 nm. To-date, the method proposed has only been tested on flat plateau-like structures. In the case of samples presenting high local slope or curvature, it would be expected that the effective spectrum be modified, as discussed in [24], requiring further investigation and a strategy for correction.

In conclusion, the ability to measure spectral reflectivity in a full-field configuration with locally resolved values has been demonstrated

experimentally using a white light interferometer. Clear identification of samples composed of two different materials has been performed at the micrometer scale. From the same interferometric stack, topography was obtained in addition to the spectral information and further corrected using known values of the phase on reflection error introduced at the reflection. This paves the way for fast characterization of spatially extended samples with micro-structured elements that require both a large FoV and high spatial resolution. In this letter, x20 objectives were used to rapidly image an area of $130x131 \,\mu\text{m}^2$ with an acquisition time <5 min and a processing time <2 min. The use of objectives with lower magnification would lead to characterizing even larger FoV while preserving the same acquisition time, but at the cost of a decreased lateral resolution. Since the acquisition and processing times are only software/hardware limited, it is expected that further work will allow significant reductions, particularly for the acquisition time so that the technique could be used with classical interferometers on standard optical tables without compromising the measurement sensitivities.

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